Vishay Semiconductors

RoHS

COMPLIANT

HEXFRED[®] Ultrafast Soft Recovery Diode, 4 A



www.vishay.com

PRODUCT SUMMARY								
Package	D-PAK (TO-252AA)							
I _{F(AV)}	4 A							
V _R	600 V							
V _F at I _F	1.8 V							
t _{rr} typ.	17 ns							
T _J max.	150 °C							
Diode variation	Single die							

FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Guaranteed avalanche
- Specified at operating temperature
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V _{RRM}		600	V						
Maximum continuous forward current	I _{F(AV)}	T _C = 100 °C	4							
Single pulse forward current	I _{FSM}		25	А						
Repetitive peak forward current	I _{FRM}	T _C = 116 °C	16							
Maximum power dissipation	PD	T _C = 100 °C	10	W						
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 150	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-					
Forward voltage See fig. 1		$I_F = 4 A$		1.5	1.8	V				
	VF	I _F = 8 A	-	1.8	2.2					
		I _F = 4 A, T _J = 125 °C	-	1.4	1.7					
Maximum reverse		V _R = V _R rated	-	0.17	3.0					
leakage current	I _R	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	44	300	μA				
Junction capacitance	CT	V _R = 200 V	-	4	8	pF				
Series inductance	Ls	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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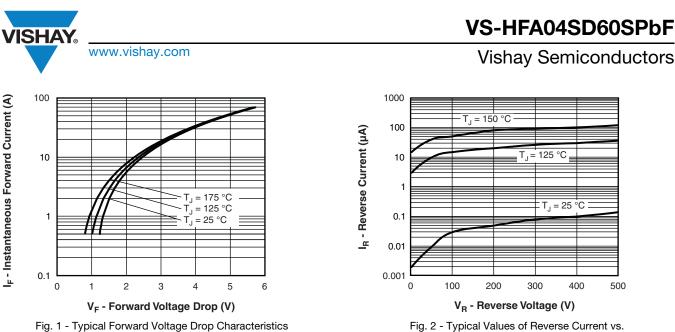
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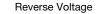
VS-HFA04SD60SPbF

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DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	200 A/µA, V _R = 30 V	-	17	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	28	42	ns		
		T _J = 125 °C	I _F = 4 A dI _F /dt = 200 A/μs V _B = 200 V	-	38	57			
Deels receivers ourrent	I _{RRM}	T _J = 25 °C		-	2.9	5.2	A nC		
Peak recovery current		T _J = 125 °C		-	3.7	6.7			
	Q _{rr}	T _J = 25 °C		-	40	60			
Reverse recovery charge		T _J = 125 °C		-	70	105	nc.		
Rate of fall of recovery current	dl _{(rec)M} /dt	T _J = 25 °C		-	280	-	• (
		T _J = 125 °C		-	235	-	A∕µs		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55	-	150	°C				
Thermal resistance, junction to case	R _{thJC}		-	-	5.0	°C/W				
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	0/11				
Weight			-	2.0	-	g				
weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style D-PAK	AK HFA04SD60S							





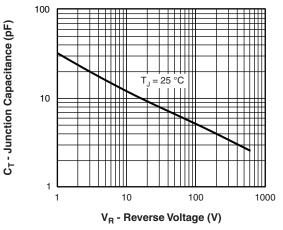


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

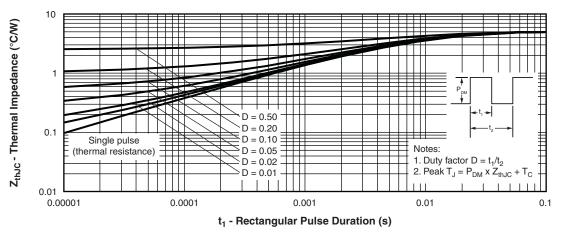


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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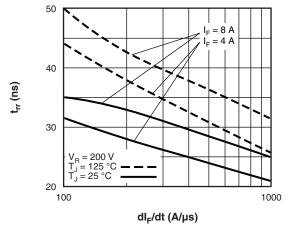
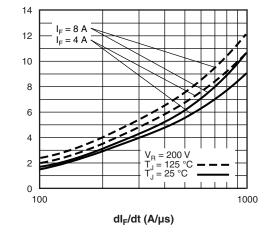


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

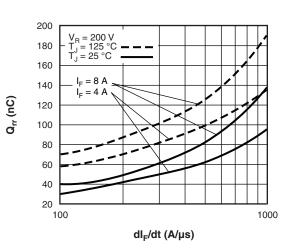


I_{RR} (A)

Fig. 6 - Typical Recovery Current vs. dl_F/dt

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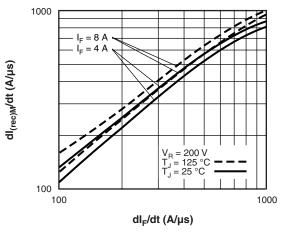


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt

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 4
 Document Number: 94034

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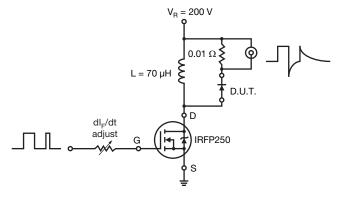
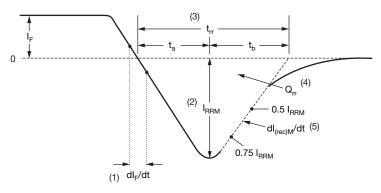


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

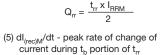


Fig. 10 - Reverse Recovery Waveform and Definitions

VS-HFA04SD60SPbF

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ORDERING INFORMATION TABLE

Device code	VS-	HF	Α	04	SD	60	S	TR	PbF	
	1	2	3	4	5	6	7	8	9	
	 Vishay Semiconductors product HEXFRED[®] family Electron irradiated Current rating (04 = 4 A) D-PAK Voltage rating (60 = 600 V) S = D-PAK 									
		 TRR = Tape and reel (right oriented) TRL = Tape and reel (left oriented) 								

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95016							
Part marking information	www.vishay.com/doc?95059							
Packaging information	www.vishay.com/doc?95033							

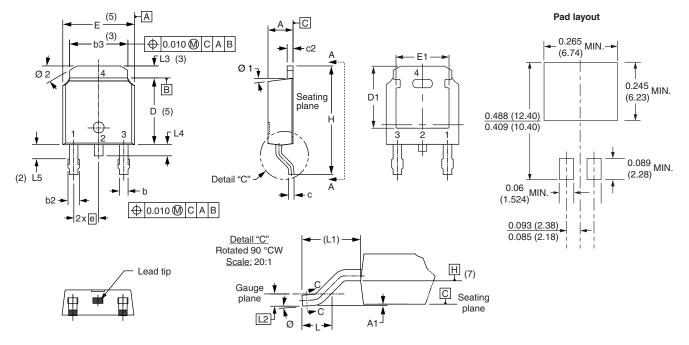






D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	ES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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